

Abstract of the Disclosure

In a TFT LCD device comprising a substrate, at least one thin film transistor
5 formed on the substrate, having a source electrode and a drain electrode, an insulating
layer formed over the whole surface of the substrate on which the thin film transistor is
formed, having at least one contact hole exposing a portion of the drain electrode, and
reflective layer pixel electrode corresponding to the thin film transistor, formed on the
insulating layer to be connected with the drain electrode through the contact hole, the
pixel electrode is formed of a multi-layered conductive layer. The drain electrode is
composed of multiple layers, and the most upper layer of the multiple layers is one
selected from a Cr layer and a MoW layer. Preferably, the multi-layered conductive
layer is composed of two-layered conductive layer having a lower layer of the same
material as that of the most upper layer and an upper layer of Al-containing metal.

TEFTO